

Brief Profile

Name:	Priyanka
Date of Birth:	4/01/1992
Educational Qualification:	
<i>Ph. D.</i>	-
<i>M. Tech</i>	NIT Rourkela, Electronic System & Comm.
<i>B. Tech</i>	UPTU, Lucknow, ECE
Work Experience:	
• <i>Teaching</i>	-
• <i>Research / Industry</i>	-
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Area/Subjects of Interest	Semiconductor Devices, FinFETs, MOSFETs, Microprocessor, Control System, Signal & System, Digital Electronics.
Teaching:	
<i>Subjects Taught at UG level</i>	-
<i>Subjects Taught at PG level</i>	-
Research Guidance	
<i>No. of Ph.D./M.Tech Guided</i>	-
Research Publications	
• Journals	5
• Conferences	2
• Book Chapters	-
Patent/IPR (Books Published etc.)	
No. of National/International Conferences attended/ Paper Presented	2
STC/FDP/Summer/Winter Schools/Workshops/Seminars attended	1
Memberships of the Professional Societies	-
Awards/Honors	M.Tech Scholar and Scored Ist Rank at PG level.
Any other relevant Information	GATE, UGCNET

LIST OF PUBLICATIONS

Journal Papers

- I. K P Pradhan, Samar K. Saha, P K Sahu, **Priyanka**, “Impact of Fin Height and Fin Angle variation on the AC performance Matrix of Hybrid FinFETs”, *IEEE Transactions of Electronic Devices* 64, 2017, no.1, pp.52-57
- II. K P Pradhan, **Priyanka**, P K Sahu, “Temperature dependency of Double Material Gate Oxide (DMGO) Symmetric Dual-k Spacer (SDS) Wavy FinFET”, *Superlattices and Microstructures, Elsevier*, 2016, vol. no.89, pp.355-361.
- III. K P Pradhan, **Priyanka**, P K Sahu, “Investigation of Asymmetric High-k Underlap Spacer (AHUS) hybrid FinFET from Temperature Perspective”, *Microsystem Technologies, Springer*, 2016 ,pp.1-6.
- IV. K P Pradhan, **Priyanka**, P K Sahu, “Study of Fin Tapering in Nanoscale Symmetric Dual-k Spacer (SDS) Hybrid FinFET”, *Material Science in Semiconductor Processing, Elsevier*, 2016. 57,185-189.
- V. K P Pradhan, **Priyanka**, Mallikarjunarao, P K Sahu, “Exploration of Symmetric High-k Spacer (SHS) Hybrid FinFET for High Performance Application.” *Superlattices and Microstructures, Elsevier*, 2016, vol. no. 90, pp.191-197.

Conference Papers:

- I. K P Pradhan, **Priyanka**, P K Sahu, “Exploration of Double Material Gate Oxide in Symmetric Dual- k Spacer Wavy FinFET”, *International Conference on Emerging Technologies: Micro to Nano (ETMN)*, Jaipur, 24-25 October, 2015.
- II. K P Pradhan, **Priyanka**, Mallikarjunarao, P K Sahu, S K Mohapatra “Analysis of Symmetric High-k Spacer (SHS) Trigate Wavy FinFET: A Novel Device”, *12th IEEE India International Conference, IEEE Indicon*, Delhi, 17-20 December, 2015.